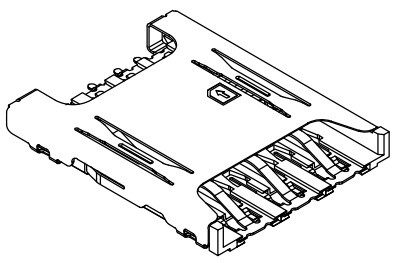
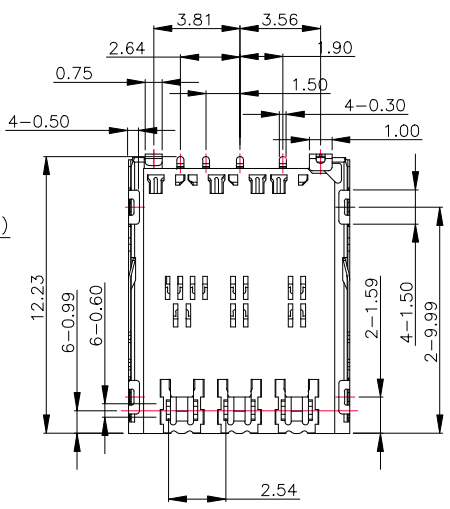
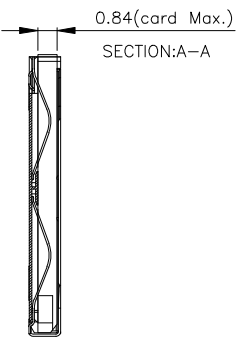
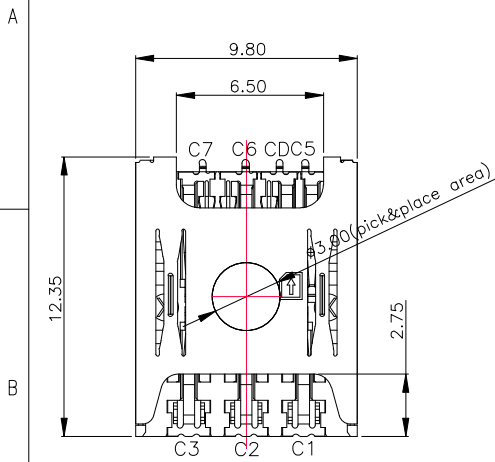
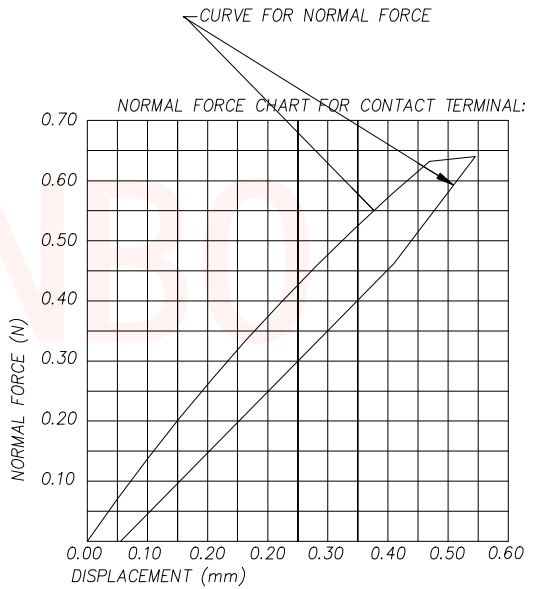
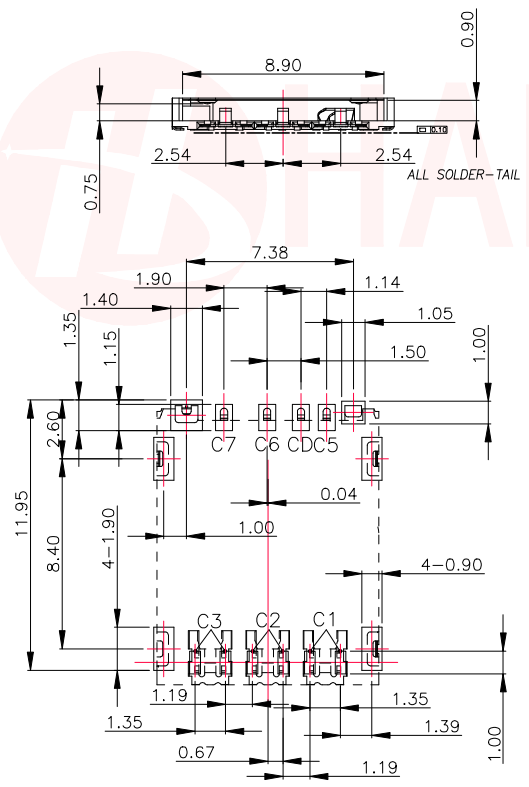
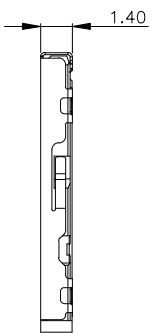
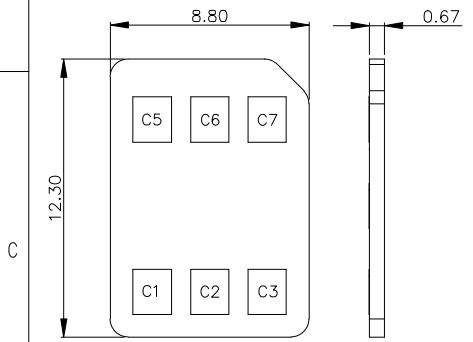




REV.	ECN NO OR DESCRIPTION	REVISED	DATE



- NOTES:
- MATERIAL: SEE TABLE
 - SPECIALITY:
 - 2.1 Rated current: 0.5A Max
 - 2.2 Rated voltage: 30V AC
 - 2.3 Contact Resistance: 100mohm MAX
 - 2.4 Insulation Resistance: 1000Mohm MIN 500V DC
 - 2.5 Dielectric withstanding voltage: 500V AC/minute.
 - 2.6 Solder ability: 250±5 10±0.5s.
 - 2.7 Durability: 5000 Cycles
 - 2.8 Mating and Unmating force
 - Insertion Force 10N Max
 - Withdrawal Fore 0.5N Min
 - 2.9 Operating Temperature: -40°C~+80°C



NANO SIM CARD	
Pin No.	NAME
C1	VCC OF SIM
C2	RST OF SIM
C3	CLK OF SIM
C5	GND OF SIM
C6	VPP OF SIM
C7	I/O OF SIM
C4/C8	N/A
CD	DETECTION SWITCH

③	TERMINAL	6	C5210-EH, T=0.12	Au 3u" PLATING
②	BASE INSULATOR	1	LCP+GF30%	BLACK
①	SHELL	1	SUS304-H, T=0.15	AU/Ni PLATING
NO.	PART NAME	Q'TY	DESCRIPTION	NOTE

UNLESS OTHERWISE SPECIFIED TOLERANCES		东莞市汉博电子科技有限公司 DONGGUAN HANBO TECHNOLOGY CO., LTD			
DECIMALS:	ANGLES:	TITLE	6Pin 1.4H PUSH PULL Nano SIM CARD CONN.		
X : ±0.38	X : ±2°	DWN	xiong	PART NO. SNO-1310	
X.X : ±0.25	X.X : ±1°	CHKD	lee	SCALE: 1:1	UNIT: mm
X.XX : ±0.15		APVD	wang	SIZE: A4	SHEET: 10F 1
				REV: A4	
CUSTOMER COPY					